





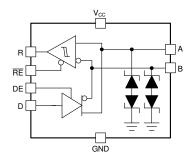


THVD2419, THVD2429 SLLSFP5 - JANUARY 2024

# THVD24x9 3V to 5.5V RS-485 Transceivers With Integrated Surge and High Bus-Fault **Protection in Small Packages**

#### 1 Features

- Meets or exceeds the requirements of the TIA/ EIA-485A standard
- 3V to 5.5V Supply Voltage
- Industry's smallest surge-integrated RS-485 device in 9mm<sup>2</sup> package
- V<sub>IO</sub> Support from 1.65V to V<sub>CC</sub> supply level
- Bus I/O protection
  - ± 2.5kV IEC 61000-4-5 1.2/50µs surge (SOIC)
  - ± 1.5kV IEC 61000-4-5 1.2/50µs surge (VSON)
  - ± 8kV IEC 61000-4-2 Contact discharge
  - ± 4kV IEC 61000-4-4 Electrical fast transient
  - ± 15kV HBM ESD
  - ± 42V DC bus fault
- Available in two speed grades
  - THVD2419: 250kbps
  - THVD2429: 20Mbps
- Extended ambient
  - temperature range: -40°C to 125°C
- Extended operational
  - common-mode range: ± 25V
- Large receiver hysteresis for noise rejection
- Low Power Consumption
  - Standby supply current: < 3μA</li>
  - Current during operation: < 5.3mA</li>
- · Glitch-free power-up and down for hot plug-in capability
- Open, short, and idle bus failsafe
- 1/8 Unit load (up to 256 bus nodes)
- Industry standard 8-pin SOIC for drop-in compatibility
- Small surge-integrated RS-485 device in 3mm x 3mm leadless (VSON) package



THVD24x9 Block Diagram (SOIC Package)

## 2 Applications

- Wireless infrastructure
- Factory automation
- Motor drives
- **Building automation**
- **HVAC**
- Grid infrastructure

## 3 Description

THVD24x9 devices half-duplex are transceivers with integrated surge protection. Surge protection is achieved by integrating transient voltage suppressor (TVS) diodes in the standard 8-pin SOIC (D) package as well as small 10-pin VSON package. This feature increases the reliability by providing better immunity to noise transients coupled to the data cable which eliminates the need for external protection components.

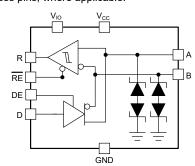
THVD24x9 devices in the standard pin-out SOIC package operate from a single

3.3V or 5V supply. In addition, THVD24x9 devices in 10-pin VSON package and the V-versions of SOIC package support an additional V<sub>IO</sub> supply to operate the IOs from as low as 1.65V supply level. The devices in this family feature a wide common-mode voltage range making them suitable for multi-point applications over long cable runs.

#### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>						
THVD2419, '2429 THVD2419V, '2429V	SOIC (8)	4.9mm × 6mm						
THVD2419, '2429	VSON (10)	3mm × 3mm						

- For more information, see Section 12. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.



THVD24x9 Block Diagram (VSON Package)



# **Table of Contents**

1 Features1	8.3 Featu
2 Applications1	8.4 Device
3 Description1	9 Application
4 Device Comparison Table3	9.1 Appli
5 Pin Configuration and Functions4	9.2 Typica
6 Specifications5	9.3 Power
6.1 Absolute Maximum Ratings5	9.4 Layou
6.2 ESD Ratings 5	10 Device a
6.3 ESD Ratings [IEC]5	10.1 Devi
6.4 Recommended Operating Conditions6	10.2 Rece
6.5 Thermal Information6	10.3 Supp
6.6 Power Dissipation6	10.4 Trade
6.7 Electrical Characteristics7	10.5 Elect
6.8 Switching Characteristics_250kbps9	10.6 Glos
6.9 Switching Characteristics_20Mbps9	11 Revision
7 Parameter Measurement Information11	12 Mechani
8 Detailed Description13	Informati
8.1 Overview	12.1 Tape
8.2 Functional Block Diagrams	

	8.3 Feature Description	. 14
	8.4 Device Functional Modes	.17
9	Application and Implementation	18
	9.1 Application Information	.18
	9.2 Typical Application	18
	9.3 Power Supply Recommendations	21
	9.4 Layout	22
1(	Device and Documentation Support	.24
	10.1 Device Support	24
	10.2 Receiving Notification of Documentation Updates	24
	10.3 Support Resources	24
	10.4 Trademarks	24
	10.5 Electrostatic Discharge Caution	.24
	10.6 Glossary	.24
11	I Revision History	24
12	2 Mechanical, Packaging, and Orderable	
	Information	
	12.1 Tape and Reel Information	.31



# **4 Device Comparison Table**

PART NUMBER	Package	V <sub>IO</sub>	SIGNALING RATE	NODES	
THVD2419	No vo to 050th o				
THVD2419V	8010.8	Yes	up to 250kbps		
THVD2429	SOIC-8	No	to 00MHz	256	
THVD2429V		Yes	up to 20Mbps		
THVD2419	VSON-10	Yes	up to 250kbps		
THVD2429	V30IN-10	165	up to 20Mbps		



# **5 Pin Configuration and Functions**

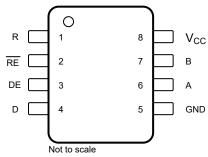


Figure 5-1. THVD2419, THVD2429, 8-Pin (SOIC) (Top View)

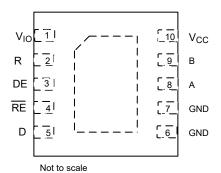


Figure 5-2. THVD2419, THVD2429, 10-Pin (VSON) (Top View)

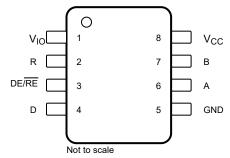


Figure 5-3. THVD2419V, THVD2429V, 8-pin (SOIC) (Top View)

		PIN		TVDE	DESCRIPTION		
NAME	SOIC-8	SOIC-8 (V <sub>IO</sub> )	VSON-10	TYPE DESCRIPTION			
V <sub>IO</sub>	-	1	1	Р	1.8V to 5V supply for R, D, and RE/DE		
R	1	2	2	0	Receiver data output		
RE	2		3	I	Receiver enable, active low (2MΩ internal pull-up)		
DE	3		4	I	Driver enable, active high		
DE/RE	-	3	-	I	Driver enable (Active high), Receiver enable (Active Low). (2 $\mbox{M}\Omega$ internal pull-down)		
D	4	4	5	I	Driver data input		
GND	5	5	6, 7	-	Device ground		
Α	6	6	8	I/O	Bus I/O port, A (complementary to B)		
В	7	7	9	I/O	Bus I/O port, B (complementary to A)		
V <sub>CC</sub>	8	8	10	Р	3.3V to 5V supply for the device		

Submit Document Feedback



## **6 Specifications**

#### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Logic supply voltage	VIO (DRC package Only)	-0.5	V <sub>CC</sub> + 0.2	V
Bus supply voltage	V <sub>CC</sub>	-0.5	6.5	V
Bus voltage	Range at any bus pin (A or B) as differential or common-mode with respect to GND	-42	42	V
Input voltage	Range at any logic pin (D, DE or $\overline{\text{RE}}$ ) Versions with VIO pin	-0.3	V <sub>IO</sub> + 0.2	V
Input voltage	Range at any logic pin (D, DE or RE) D Package	-0.3	V <sub>CC</sub> + 0.2	V
Receiver output current	Io	-24	24	mA
Storage temperature	T <sub>stg</sub>	-65	170	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

#### 6.2 ESD Ratings

				±16,000	UNIT
V <sub>(ESD)</sub> Elect		Human-body model (HBM), per ANSI/ESDA/	Bus terminals and GND	±16,000	V
V <sub>(ESD)</sub>	Electrostatic discharge	JEDEC JS-001 <sup>(1)</sup>	All pins except bus terminals and GND	±4,000	V
		Charged-device model (CDM), per JEDEC specif	ication JESD22-C101 <sup>(2)</sup>	±1,500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

# 6.3 ESD Ratings [IEC]

				VALUE	UNIT	
V	Electrostatic discharge, bus	Contact discharge, per IEC 61000-4-2	Bus terminals and GND	±8,000	V	
V <sub>(ESD)</sub>	terminals	Air-gap discharge, per IEC 61000-4-2	Bus terminals and GND	±8,000	V	
V <sub>(SURGE)</sub>	Surge	Per IEC 61000-4-5, 1.2/50-8/20 µs CWG (DRC Package)	Bus terminals and GND	±1,500	V	
V <sub>(SURGE)</sub>	terminals  Surge	Per IEC 61000-4-5, 1.2/50-8/20 µs CWG (D Package)	Bus terminals and GND	±2,500	V	



## **6.4 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM MAX	UNIT
V <sub>CC</sub>	Supply voltage		3	5.5	V
V <sub>IO</sub>	I/O supply voltage (DRC Package)		1.65	V <sub>CC</sub>	: V
V <sub>IH</sub>	High-level input voltage (driver, driver enable, receiver enable and slew rate select inputs)	DPC Package D package with VIO antion	0.7*V <sub>IO</sub>	V <sub>IC</sub>	V
V <sub>IL</sub>	Low-level input voltage (driver, driver enable, receiver enable and slew rate select inputs)	DRC Package, D package with VIO option  D Package without VIO option  Darately or common mode) <sup>(1)</sup> V <sub>IO</sub> = 1.8V or 2.5V (Devices with VIO pin)  V <sub>IO</sub> = 3.3V or 5V (Devices with VIO pin)  THVD2419 THVD2429	0	0.3*V <sub>IC</sub>	V
V <sub>IH</sub>	High-level input voltage (driver, driver enable, receiver enable and slew rate select inputs)	,	0.7*V <sub>CC</sub>	Vcc	· V
V <sub>IL</sub>	Low-level input voltage (driver, driver enable, receiver enable and slew rate select inputs)		0	0.3*VCC	V
VI	Input voltage at any bus terminal (se	parately or common mode) <sup>(1)</sup>	-25	25	V
V <sub>ID</sub>	Differential input voltage		-25	25	V
Io	Output current, driver		-60	60	mA
I <sub>OR</sub>	Output current, receiver	V <sub>IO</sub> = 1.8V or 2.5V (Devices with VIO pin)	-4	4	mA
I <sub>OR</sub>	Output current, receiver	V <sub>IO</sub> = 3.3V or 5V (Devices with VIO pin)	-8	3	mA
R <sub>L</sub>	Differential load resistance		54	60	Ω
4 /4	Cianalina rata	THVD2419		250	kbps
1/t <sub>UI</sub>	Signaling rate	THVD2429		20	Mbps
T <sub>A</sub>	Operating ambient temperature		-40	125	°C
TJ	Junction temperature		-40	150	°C

<sup>(1)</sup> The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

#### **6.5 Thermal Information**

		THVD2419,		
$ \begin{array}{c c} \textbf{THERMAL METRIC}^{(1)} \\ \hline \\ R_{\text{BJA}} & \text{Junction-to-ambient thermal resistance} \\ \hline \\ R_{\text{BJC}(top)} & \text{Junction-to-case (top) thermal resistance} \\ \hline \\ R_{\text{BJB}} & \text{Junction-to-board thermal resistance} \\ \hline \\ \psi_{JT} & \text{Junction-to-top characterization parameter} \\ \hline \\ \psi_{JB} & \text{Junction-to-board characterization parameter} \\ \hline \end{array} $	THERMAL METRIC <sup>(1)</sup>	DRC (VSON)	D (SOIC)	UNIT
		10 PINS	8 PINS  117.2  40.2  65.3	
R <sub>0JA</sub>	Junction-to-ambient thermal resistance	65.2	117.2	°C/W
R <sub>0</sub> JC(top)	Junction-to-case (top) thermal resistance	41.7	40.2	°C/W
R <sub>0JB</sub>	Junction-to-board thermal resistance	36.4	65.3	°C/W
Ψлт	Junction-to-top characterization parameter	1.4	3.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	36.3	64.4	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	24.9	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 6.6 Power Dissipation

	PARAMETER	TEST CONDITI	ONS		VALUE	UNIT
	Driver and receiver enabled,	Unterminated	THVD2419	250 kbps	258	mW
		$R_L = 300\Omega$ , $C_L = 50pF$ (driver)	THVD2429	20Mbps	335	1 11100
D D		RS-422 load R <sub>L</sub> = 100 $\Omega$ , C <sub>L</sub> = 50pF (driver)	THVD2419	250 kbps	273	mW
P <sub>D</sub>	V <sub>CC</sub> = 5.5 V, T <sub>A</sub> = 125 °C, square wave at 50% duty cycle		THVD2429	20Mbps	325	
		RS-485 load R <sub>L</sub> = $54\Omega$ , C <sub>L</sub> = $50pF$ (driver)	THVD2419	250 kbps	315	mW
			THVD2429	20Mbps	355	IIIVV

Product Folder Links: THVD2419 THVD2429



#### **6.7 Electrical Characteristics**

over operating free-air temperature range (unless otherwise noted). All typical values are at  $25^{\circ}$ C and supply voltage of  $V_{CC}$  = 5V,  $V_{IO}$  = 3.3V, unless otherwise noted.

, -	= 3.3V , unless otherw PARAMETER	TEST CONDITION	S		MIN	TYP	MAX	UNIT
Driver	I ANAME I EIN	1201 CONDITION			IVIIIV		IIIAA	Oldin
Dilvei		$R_L = 60\Omega$ , $-25V \le V_{test} \le 25V$ (See Figure 7-1)			1.5	2.8		V
	D. 1155	$R_L = 60\Omega$ , $-25V \le V_{test} \le 25V$ , $4.5V \le V_{CC} \le 5.5$	V (See F	igure 7-1)	2.1			
$ V_{OD} $	Driver differential output voltage magnitude	$R_L = 100\Omega$ (See Figure 7-2)	v (See 1	igure 7-1)	2.1	2.8 3.3 2.9 2.5 50 V <sub>CC</sub> /2 3 50 75 125 200 250 -60 -300 125 200 -125 -40 250 -125 -40 250 -125 -40 50 V <sub>IO</sub> - 0.2 0.2 0.2 0.4 1 55 170 10 2.3 2.6 2.2 170		
	Voltago magnitudo							
	Ob i diff di-1 d d	R <sub>L</sub> = 54Ω (See Figure 7-2)			1.5	2.5		
$\Delta  V_{OD} $	Change in differential output voltage	$R_L$ = 54Ω or 100Ω (See Figure 7-2)			-50		50	mV
V <sub>OC</sub>	Common-mode output voltage	$R_L$ = 54Ω or 100Ω (See Figure 7-2)			1	V <sub>CC</sub> /2	3	V
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage	$R_L$ = 54Ω or 100Ω (See Figure 7-2)			-50		50	mV
I <sub>os</sub>	Short-circuit output current	DE = $V_{IO}$ , -42V $\leq$ ( $V_A$ or $V_B$ ) $\leq$ 42V, or A shorted	l to B		-250		250	mA
Receiver	1							
			V	' <sub>I</sub> = 12 V		75	125	μA
		DE 0777 177 277 277	V	' <sub>I</sub> = 25 V		200	250	μA
I <sub>I</sub>	Bus input current	DE = 0 V, V <sub>CC</sub> and V <sub>IO</sub> = 0 V or 5.5 V	V	′ <sub>I</sub> = -7 V	-100	-60		μA
			V	′ <sub>I</sub> = –25 V	-350	-300		μA
V <sub>TH+</sub>	Positive-going input threshold voltage <sup>(1)</sup>				40	125	200	mV
V <sub>TH-</sub>	Negative-going input threshold voltage <sup>(1)</sup>	Over common-mode range of ± 25 V			-200	-125	-40	mV
V <sub>HYS</sub>	Input hysteresis					250		mV
V <sub>TH FSH</sub>	Input fail-safe threshold				-40		40	mV
C <sub>A,B</sub>	Input differential capacitance	Measured between A and B, f = 1 MHz				50		pF
V <sub>OH</sub>	Output high voltage	I <sub>OH</sub> = -8 mA, V <sub>IO</sub> = 3 to 3.6 V or 4.5 V to 5.5 V	· 		V <sub>IO</sub> - 0.4	V <sub>IO</sub> – 0.2		V
V <sub>OL</sub>	Output low voltage	I <sub>OL</sub> = 8 mA, V <sub>IO</sub> = 3 to 3.6 V or 4.5 V to 5.5 V			- 10		0.4	V
V <sub>OH</sub>	Output high voltage	I <sub>OH</sub> = -4 mA, V <sub>IO</sub> = 1.65 to 1.95 V or 2.25 V to 2	2.75 V		V <sub>10</sub> - 0.4	V <sub>IO</sub> – 0.2		V
V <sub>OL</sub>	Output low voltage	I <sub>OL</sub> = 4 mA, V <sub>IO</sub> = 1.65 to 1.95 V or 2.25 V to 2.			- 10		0.4	V
I <sub>OZ</sub>	Output high-impedance current, R pin	$V_O = 0 \text{ V or } V_{IO}, \overline{RE} = V_{IO}$			-1		1	μA
Logic	ourions, it pin							
I <sub>IN</sub>	Input current (DE , SLR)	DRC: $1.65 \text{ V} \le \text{V}_{\text{IO}} \le 5.5 \text{ V}, 0 \text{ V} \le \text{V}_{\text{IN}} \le \text{V}_{\text{IO}}$ D: $3 \text{ V} \le \text{V}_{\text{CC}} \le 5.5 \text{ V}, 0 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}$					5	μA
I <sub>IN</sub>	Input current (D, RE)	DRC: $1.65 \text{ V} \le \text{V}_{IO} \le 5.5 \text{ V}$ , $0 \text{ V} \le \text{V}_{IN} \le \text{V}_{IO}$ D: $3 \text{ V} \le \text{V}_{CC} \le 5.5 \text{ V}$ , $0 \text{ V} \le \text{V}_{IN} \le 5.5 \text{ V}$			-5			μA
Thermal F	Protection	D. 3 V 3 VCC 3 3.3 V, O V 3 V N 3 3.3 V						
	Thermal shutdown							
T <sub>SHDN</sub>	threshold	Temperature rising			150	170		°C
T <sub>HYS</sub>	Thermal shutdown hysteresis					10		°C
Supply								
UV <sub>VCC</sub> (rising)	Rising under-voltage threshold on V <sub>CC</sub>					2.3	2.6	V
UV <sub>VCC</sub>	Falling under-voltage threshold on V <sub>CC</sub>				1.95	2.2		V
UV <sub>VCC(hys</sub>	Hysteresis on under-voltage of V <sub>CC</sub>					170		mV
UV <sub>VIO</sub>	Rising under-voltage threshold on V <sub>IO</sub>					1.4	1.6	V
UV <sub>VIO</sub>	Falling under-voltage				1.2	1.3		V



over operating free-air temperature range (unless otherwise noted). All typical values are at 25°C and supply voltage of  $V_{CC}$  = 5V,  $V_{IC}$  = 3.3V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
UV <sub>VIO(hys)</sub>	Hysteresis on under-voltage of V <sub>IO</sub>			120		mV	
		Driver and receiver enabled	RE = 0 V, DE = V <sub>IO</sub> , No load		3.5	5.3	mA
		Driver enabled, receiver disabled	$\overline{RE} = V_{IO}$ , DE = $V_{IO}$ , No load		2.5	4.2	mA
СС	Supply current (quiescent), V <sub>CC</sub> = 4.5 V to 5.5 V	Driver disabled, receiver enabled	RE = 0 V, DE = 0 V, No load		1.8	2.4	mA
		Driver and receiver disabled (D package, no VIO pin)	RE = V <sub>CC</sub> , DE = 0 V, D = open, No load		0.1	5	μA
	Driver and receiver disabled (DRC paclkage, with VIO pin)	RE = V <sub>IO</sub> , DE = 0 V, D = open, No load		0.1	3	μA	
		Driver and receiver enabled	RE = 0 V, DE = V <sub>IO</sub> , No load		3	4.1	mA
		Driver enabled, receiver disabled	$\overline{RE} = V_{IO}$ , DE = $V_{IO}$ , No load		2	3	mA
СС	Supply current (quiescent), V <sub>CC</sub> = 3 V to 3.6 V	Driver disabled, receiver enabled	RE = 0 V, DE = 0 V, No load		1.6	2.2	mA
		Driver and receiver disabled (D Package, no VIO)	RE = V <sub>CC</sub> , DE = 0 V, D = open, No load		TBD	4	μΑ
		Driver and receiver disabled (DRC package, with VIO pin)	RE = V <sub>IO</sub> , DE = 0 V, D = open, No load		TBD	2	μA
	Logic supply current	Driver disabled, Receiver enabled	DE = 0 V, RE = 0 V, No load		3.3	8.4	μΑ
Ю	(quiescent), V <sub>IO</sub> = 3 to 3.6 V, DRC Package	Driver disabled, Receiver disabled	DE = 0 V, RE = V <sub>IO</sub> , No load		0.1	2	μΑ

(1) Under any specific conditions,  $V_{TH+}$  is specified to be at least  $V_{HYS}$  higher than  $V_{TH-}$ .

Submit Document Feedback



#### 6.8 Switching Characteristics\_250kbps

250-kbps (THVD2419) over recommended operating conditions. All typical values are at 25°C and supply voltage of  $V_{CC}$  = 5 V ,  $V_{IO}$  = 3.3 V, unless otherwise noted. (1)

	PARAMETER	TEST COND	ITIONS	MIN	TYP	MAX	UNIT
Driver							
	Differential output rise/fall time		V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3V	400	650	1200	ns
t <sub>r</sub> , t <sub>f</sub>	Dinerential output rise/fail time		V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V	500	710	1200	ns
	Propagation delay	$R_L = 54 \Omega, C_L = 50 pF$	V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3V		525	750	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Pulse skew,  t <sub>PHL</sub> - t <sub>PLH</sub>	See Figure 7-3	V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V		560	770	ns
<b>.</b>			V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3V		30	70	ns
t <sub>SK(P)</sub>	ruise skew, [tpHL – tpLH]		V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V		30	70	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable time	RE = X			33	75	ns
	Enable time	RE = 0 V	See Figure 7-4 and		TBD	280	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	Enable time	RE = V <sub>IO</sub>	Figure 7-5		2	4.5	μs
t <sub>SHDN</sub>	Time to shutdown	RE = V <sub>IO</sub>		50		500	ns
Receiver							
t <sub>r</sub> , t <sub>f</sub>	Output rise/fall time				13	20	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation delay	C <sub>L</sub> = 15 pF	See Figure 7-6		850	1270	ns
t <sub>SK(P)</sub>	Pulse skew,  t <sub>PHL</sub> - t <sub>PLH</sub>				5	45	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable time	DE = X			30	40	ns
		$V_{IO} = 3 \text{ V to } 3.6 \text{ V; DE} = V_{IO}$			90	120	ns
t <sub>PZH(1)</sub>	Enable time	$V_{IO}$ = 1.65 V to 1.95 V, DE = $V_{IO}$	Coo Figure 7.7		TBD	130	ns
	Enable time	$V_{IO}$ = 3 V to 3.6 V; DE = $V_{IO}$	See Figure 7-7	-	900	1320	ns
t <sub>PZL(1)</sub>		V <sub>IO</sub> = 1.65 V to 1.95 V; DE = V <sub>IO</sub>			TBD	1320	ns
t <sub>PZH(2)</sub> , t <sub>PZL(2)</sub>	Enable time	DE = 0 V	See Figure 7-8		3.3	5.4	μs
t <sub>D(OFS)</sub>	Delay to enter fail-safe operation	C = 15 pE	See Figure 7-9	7	11	18	μs
t <sub>D(FSO)</sub>	Delay to exit fail-safe operation	- C <sub>L</sub> = 15 pF	See rigule 1-8	540	850	1260	ns
t <sub>SHDN</sub>	Time to shutdown	DE = 0 V	See Figure 7-8	50		500	ns

<sup>(1)</sup> A, B are driver output and receiver input terminals for Half duplex devices. A, B are RX input, Y/Z are driver output terminals for Full duplex device

## 6.9 Switching Characteristics\_20Mbps

20-Mbps (THVD2429) over recommended operating conditions. All typical values are at 25°C and supply voltage of  $V_{CC}$  = 5 V,  $V_{IO}$  = 3.3 V, unless otherwise noted. (1)

	PARAMETER	TEST C	ONDITIONS	MIN	TYP	MAX	UNIT
Driver							
t <sub>r</sub> , t <sub>f</sub> Differential output rise/fall	Differential output via a fall time		V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3 V	4	8	15	ns
	Dinerential output rise/fail time		V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V	4	TBD	15	ns
	Danie a matteria de la co	$R_L = 54 \Omega, C_L = 50 pF$	V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3 V	6	15	30	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation delay	See Figure 7-3	V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V	6	TBD	26	ns
<b>.</b>	Pulse skew,  t <sub>PHI</sub> - t <sub>PLH</sub>		V <sub>CC</sub> = 3 to 3.6 V, Typical at 3.3 V		TBD	3	ns
t <sub>SK(P)</sub>	ruise skew,  tpHL - tpLH		V <sub>CC</sub> = 4.5 to 5.5 V, Typical at 5 V		TBD	3	ns



20-Mbps (THVD2429) over recommended operating conditions. All typical values are at 25°C and supply voltage of  $V_{CC}$  = 5 V,  $V_{IO}$  = 3.3 V, unless otherwise noted. (1)

	PARAMETER	TEST C	TEST CONDITIONS				UNIT	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable time	RE = X			15	35	ns	
	Enable time	RE = 0 V	See Figure 7-4		8	39	ns	
t <sub>PZH</sub> , t <sub>PZL</sub> Enable tii	Enable time	RE = V <sub>IO</sub>	and Figure 7-5		2	4.5	μs	
t <sub>SHDN</sub>	Time to shutdown	RE = V <sub>IO</sub>		50		500	ns	
Receiver			<u>'</u>					
t <sub>r</sub> , t <sub>f</sub>	Output rise/fall time	C <sub>L</sub> = 15 pF			1.5	6	ns	
	ալ. tթ. ս Propagation delay	V <sub>IO</sub> = 3 V to 3.6 V,	See Figure 7.6	TBD	40	57	ns	
lPHL, lPLH		V <sub>IO</sub> = 1.65 V to 1.95 V,	See Figure 7-6	TBD	TBD	60	ns	
t <sub>SK(P)</sub>	Pulse skew,  t <sub>PHL</sub> - t <sub>PLH</sub>	C <sub>L</sub> = 15 pF				5.5	ns	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable time	DE = X			11	22	ns	
t <sub>PZH(1)</sub> , t <sub>PZL(1)</sub>	Enable time	DE = V <sub>IO</sub>	See Figure 7-7		55	82	ns	
$t_{PZH(2)}$ , $t_{PZL(2)}$	Enable time	DE = 0 V	See Figure 7-8		1.5	4.5	μs	
t <sub>D(OFS)</sub>	Delay to enter fail-safe operation	C <sub>1</sub> = 15 pF	See Figure 7-9	7	11	18	μs	
t <sub>D(FSO)</sub>	Delay to exit fail-safe operation	OL - 13 PI	See rigule 7-9	19	25	50	ns	
t <sub>SHDN</sub>	Time to shutdown	DE = 0 V	See Figure 7-8	50		500	ns	

(1) A, B are driver output and receiver input terminals for Half duplex devices. A, B are RX input, Y/Z are driver output terminals for Full duplex device

Submit Document Feedback



#### 7 Parameter Measurement Information

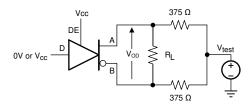


Figure 7-1. Measurement of Driver Differential Output Voltage With Common-Mode Load



Figure 7-2. Measurement of Driver Differential and Common-Mode Output With RS-485 Load

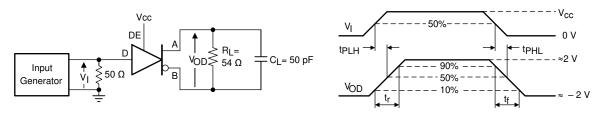


Figure 7-3. Measurement of Driver Differential Output Rise and Fall Times and Propagation Delays

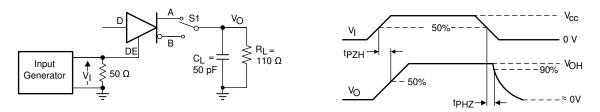


Figure 7-4. Measurement of Driver Enable and Disable Times With Active High Output and Pull-Down Load

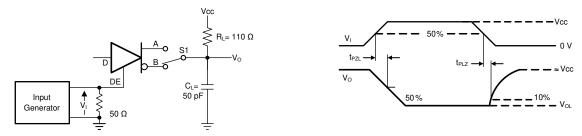


Figure 7-5. Measurement of Driver Enable and Disable Times With Active Low Output and Pull-up Load



3 V

Figure 7-6. Measurement of Receiver Output Rise and Fall Times and Propagation Delays

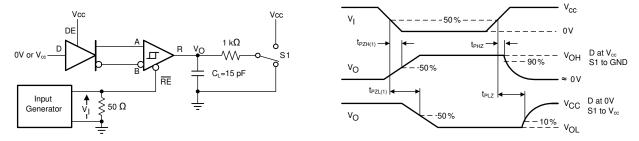


Figure 7-7. Measurement of Receiver Enable/Disable Times With Driver Enabled

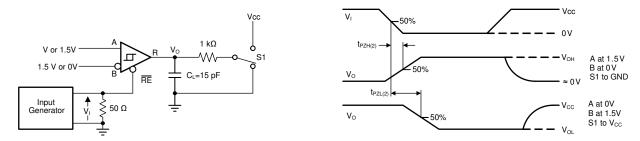
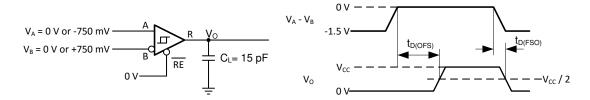


Figure 7-8. Measurement of Receiver Enable Times With Driver Disabled



Copyright © 2017, Texas Instruments Incorporated

Figure 7-9. Fail-Safe Delay Measurements

Submit Document Feedback



## **8 Detailed Description**

#### 8.1 Overview

THVD24x9 devices are surge-protected, half duplex RS-485 transceivers available in two speed grades suitable for data transmission up to 250kbps and 12Mbps respectively. Surge protection is achieved by integrating transient voltage suppressor (TVS) diodes in the standard 8-pin SOIC (D) package and a small 10-pin leadless package.

THVD2419 and THVD2429 devices have active-high driver enables and active-low receiver enables. A low standby current can be achieved by disabling both driver and receiver. THVD2419V and THVD2429V devices in the SOIC package have a single enable/disable pin (DE/RE) that either enables the driver or the receiver at a time.

## 8.2 Functional Block Diagrams

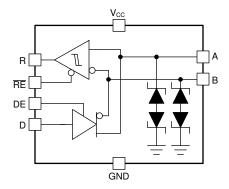


Figure 8-1. THVD2419 and THVD2429 Block Diagram (SOIC Package)

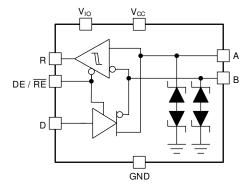


Figure 8-2. THVD2419V and THVD2429V Block Diagram (SOIC Package with VIO pin)

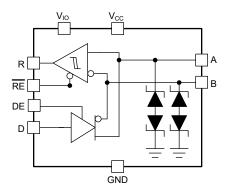


Figure 8-3. THVD2419 and THVD2429 Block Diagram (VSON Package)



#### 8.3 Feature Description

#### 8.3.1 Electrostatic Discharge (ESD) Protection

The bus pins of the THVD24x9 transceiver family include on-chip ESD protection against  $\pm 15$ kV HBM and  $\pm 8$ kV IEC 61000-4-2 contact discharge. The International Electrotechnical Commission (IEC) ESD test is far more severe than the HBM ESD test. The 50% higher charge capacitance,  $C_{(S)}$ , and 78% lower discharge resistance,  $R_{(D)}$ , of the IEC model produce significantly higher discharge currents than the HBM model. As stated in the IEC 61000-4-2 standard, contact discharge is the preferred transient protection test method.

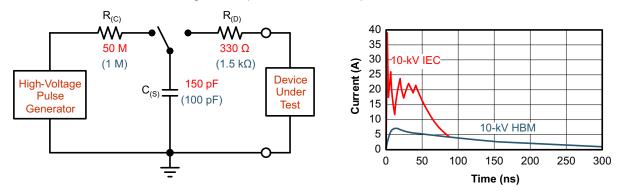


Figure 8-4. HBM and IEC ESD Models and Currents in Comparison (HBM Values in Parenthesis)

The on-chip implementation of IEC ESD protection significantly increases the robustness of equipment. Common discharge events occur because of human contact with connectors and cables.

#### 8.3.2 Electrical Fast Transient (EFT) Protection

Inductive loads such as relays, switch contactors, or heavy-duty motors can create high-frequency bursts during transition. The IEC 61000-4-4 test is intended to simulate the transients created by such switching of inductive loads on AC power lines. Figure 8-5 shows the voltage waveforms in to  $50\Omega$  termination as defined by the IEC standard.

Submit Document Feedback



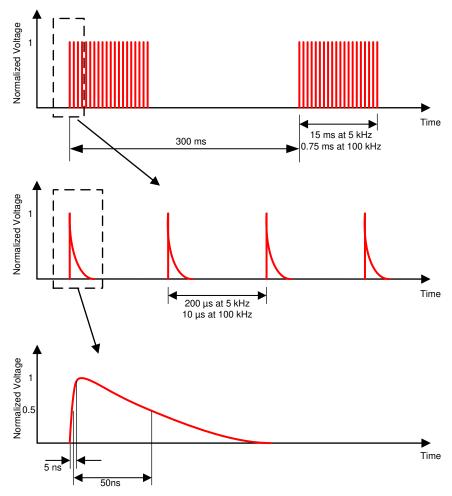


Figure 8-5. EFT Voltage Waveforms

Internal ESD protection circuits of the THVD24x9(V) protect the transceivers against ±4kV EFT. With careful system design, one could achieve EFT Criterion A (no data loss when transient noise is present).

#### 8.3.3 Surge Protection

Surge transients often result from lightning strikes (direct strike or an indirect strike which induce voltages and currents), or the switching of power systems, including load changes and short circuit switching. These transients are often encountered in industrial environments, such as factory automation and power-grid systems.

Figure 8-6 compares the pulse-power of the EFT and surge transients with the power caused by an IEC ESD transient. The diagram on the left shows the relative pulse-power for a 0.5kV surge transient and 4kV EFT transient, both of which dwarf the 10kV ESD transient visible in the lower-left corner. 500V surge transients are representative of events that may occur in factory environments in industrial and process automation.

The diagram on the right shows the pulse-power of a 6kV surge transient, relative to the same 0.5kV surge transient. 6kV surge transients are most likely to occur in power generation and power-grid systems.



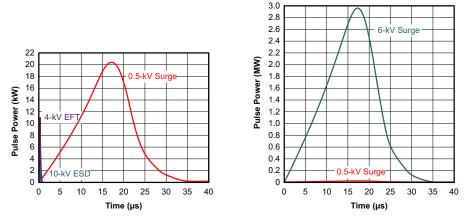


Figure 8-6. Power Comparison of ESD, EFT, and Surge Transients

Figure 8-7 shows the test setup used to validate THVD24x9 surge performance according to the IEC 61000-4-5 1.2/50µs surge pulse.

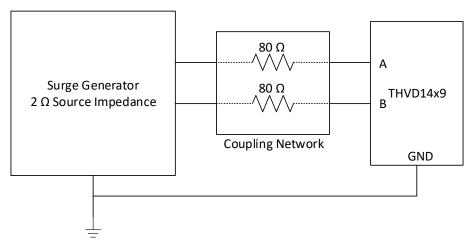


Figure 8-7. THVD24x9 Surge Test Setup

THVD24x9 product family is robust up to ±2.5kV surge transients without the need for any external components. The bus pin voltage is clamped by the integrated surge protection diodes such that the internal circuitry is not damaged during the surge event.

#### 8.3.4 Enhanced Receiver Noise Immunity

The differential receivers of THVD24x9(V) family feature fully symmetric thresholds to maintain duty cycle of the signal even with small input amplitudes. In addition, 250mV (typical) hysteresis displays excellent noise immunity.

#### 8.3.5 Failsafe Receiver

The differential receivers of the THVD24x9 family are failsafe to invalid bus states caused by the following:

- Open bus conditions, such as a disconnected connector
- Shorted bus conditions, such as cable damage shorting the twisted-pair together
- Idle bus conditions that occur when no driver on the bus is actively driving

In any of these cases, the receiver outputs a fail-safe logic high state if the input amplitude stays for longer than  $t_{D(OFS)}$  at less than  $|V_{TH}|_{FSH}$ .

Product Folder Links: THVD2419 THVD2429



#### 8.4 Device Functional Modes

When the driver enable pin, DE, is logic high, the differential outputs A and B follow the logic states at data input D. A logic high at D causes A to turn high and B to turn low. The differential output voltage defined as  $V_{OD} = V_A - V_B$  is positive. When D is low, the output states reverse: B turns high, A becomes low, and  $V_{OD}$  is negative.

When DE is low, both outputs turn high-impedance. In this condition the logic state at D is irrelevant. The DE pin has an internal pull-down resistor to ground. When left open the driver is disabled (high-impedance) by default. The D pin has an internal pull-up resistor to  $V_{CC}$ ; thus, when left open while the driver is enabled, output A turns high and B turns low.

	Table 6-1. Driver Function Table									
INPUT	ENABLE	OUTI	PUTS	FUNCTION						
D	DE	Α	В	FUNCTION						
Н	Н	Н	L	Actively drive bus high						
L	Н	L	Н	Actively drive bus low						
X	L	Z	Z Z Driver disabled							
Х	OPEN	Z Z		Driver disabled by default						
ODEN	П	ш	1	Activaly drive bus high by default						

Table 8-1. Driver Function Table

When the receiver enable pin,  $\overline{RE}$ , is logic low, the receiver is enabled. When the differential input voltage defined as  $V_{ID} = V_A - V_B$  is higher than the positive input threshold,  $V_{TH+}$ , the receiver output, R, turns high. When  $V_{ID}$  is lower than the negative input threshold,  $V_{TH-}$ , the receiver output, R, turns low. If  $V_{ID}$  is between  $V_{TH+}$  and  $V_{TH-}$  the output is indeterminate.

When  $\overline{RE}$  is logic high or left open, the receiver output is high-impedance and the magnitude and polarity of  $V_{ID}$  are irrelevant. Internal biasing of the receiver inputs causes the output to go failsafe-high when the transceiver is disconnected from the bus (open-circuit), the bus lines are shorted to one another (short-circuit), or the bus is not actively driven (idle bus).

**DIFFERENTIAL INPUT ENABLE OUTPUT FUNCTION**  $V_{ID} = V_A - V_B$ RE R  $V_{TH+} < V_{ID}$ L Н Receive valid bus high  $V_{TH-} < V_{ID} < V_{TH+}$ L Indeterminate Indeterminate bus state  $V_{ID} < V_{TH-}$ L L Receive valid bus low Н Ζ Receiver disabled Х **OPEN** Ζ Receiver disabled by default Open-circuit bus L Н Fail-safe high output Н Short-circuit bus L Fail-safe high output Idle (terminated) bus L Н Fail-safe high output

Table 8-2. Receiver Function Table



## 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 9.1 Application Information

THVD24x9 are half-duplex RS-485 transceivers with integrated system-level surge protection. Standard 8-pin SOIC (D) package allows drop-in replacement into existing systems and eliminate system-level protection components.

#### 9.2 Typical Application

An RS-485 bus consists of multiple transceivers connecting in parallel to a bus cable. To eliminate line reflections, each cable end is terminated with a termination resistor,  $R_T$ , with a value that matches the characteristic impedance,  $Z_0$ , of the cable. This method, known as parallel termination, allows for higher data rates over longer cable length.

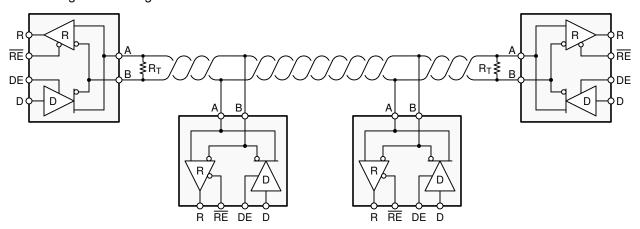


Figure 9-1. Typical RS-485 Network With Half-Duplex Transceivers

#### 9.2.1 Design Requirements

RS-485 is a robust electrical standard suitable for long-distance networking that may be used in a wide range of applications with varying requirements, such as distance, data rate, and number of nodes.

#### 9.2.1.1 Data Rate and Bus Length

There is an inverse relationship between data rate and cable length, which means the higher the data rate, the short the cable length; and conversely, the lower the data rate, the longer the cable length. While most RS-485 systems use data rates between 10kbps and 100kbps, some applications require data rates up to 250kbps at distances of 4000 feet and longer. Longer distances are possible by allowing for small signal jitter of up to 5 or 10%.

Product Folder Links: THVD2419 THVD2429



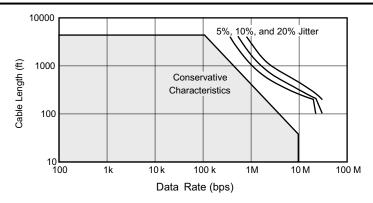


Figure 9-2. Cable Length vs Data Rate Characteristic

Even higher data rates are achievable (that is, 12Mbps for the THVD2429(V)) in cases where the interconnect is short enough (or has suitably low attenuation at signal frequencies) to not degrade the data.

#### 9.2.1.2 Stub Length

When connecting a node to the bus, the distance between the transceiver inputs and the cable trunk, known as the stub, should be as short as possible. Stubs present a non-terminated piece of bus line which can introduce reflections as the length of the stub increases. As a general guideline, the electrical length, or round-trip delay, of a stub should be less than one-tenth of the rise time of the driver, thus giving a maximum physical stub length as shown in Equation 1.

$$L_{(STUB)} \le 0.1 \times t_r \times v \times c \tag{1}$$

#### where

- t<sub>r</sub> is the 10/90 rise time of the driver
- c is the speed of light (3 ×  $10^8$  m/s)
- v is the signal velocity of the cable or trace as a factor of c

#### 9.2.1.3 Bus Loading

The RS-485 standard specifies that a compliant driver must be able to driver 32 unit loads (UL), where 1 unit load represents a load impedance of approximately 12kΩ. Because the THVD24x9(V) devices consist of 1/8 UL transceivers, connecting up to 256 receivers to the bus is possible.



#### 9.2.2 Detailed Design Procedure

RS-485 transceivers operate in noisy industrial environments typically require surge protection at the bus pins. Figure 9-3 compares 4kV surge protection implementation with a regular RS-485 transceiver (such as THVD14x0) against with the THVD24x9(V). The internal TVS protection of the THVD24x9(V) achieves ±2.5kV IEC 61000-4-5 surge protection (SOIC package) without any additional external components, reducing system level bill of materials.

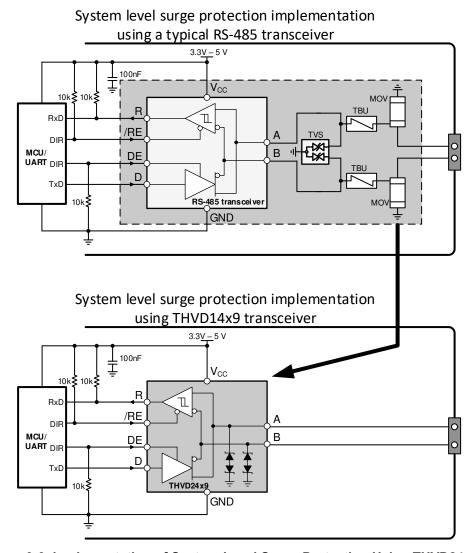
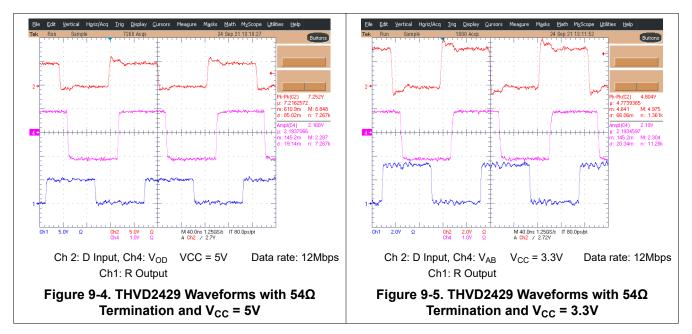


Figure 9-3. Implementation of System-Level Surge Protection Using THVD24x9(V)

Submit Document Feedback



## 9.2.3 Application Curves



#### 9.3 Power Supply Recommendations

For reliable operation at all data rates and supply voltages, each supply should be decoupled with a 100nF ceramic capacitor located as close to the supply pins as possible. This helps to reduce supply voltage ripple present on the outputs of switched-mode power supplies and also helps to compensate for the resistance and inductance of the PCB power planes.



#### 9.4 Layout

#### 9.4.1 Layout Guidelines

Additional external protection components generally are not needed when using THVD24x9 transceivers.

- 1. Use  $V_{CC}$  and ground planes to provide low-inductance. Note that high-frequency currents tend to follow the path of least impedance and not the path of least resistance. Apply 100nF to 220nF decoupling capacitors as close as possible to the  $V_{CC}$  pins of transceiver, UART and/or controller ICs on the board.
- 2. Use at least two vias for V<sub>CC</sub> and ground connections of decoupling capacitors to minimize effective via inductance.
- 3. Use  $1k\Omega$  to  $10k\Omega$  pull-up and pull-down resistors for enable lines to limit noise currents in these lines during transient events.

#### 9.4.2 Layout Example

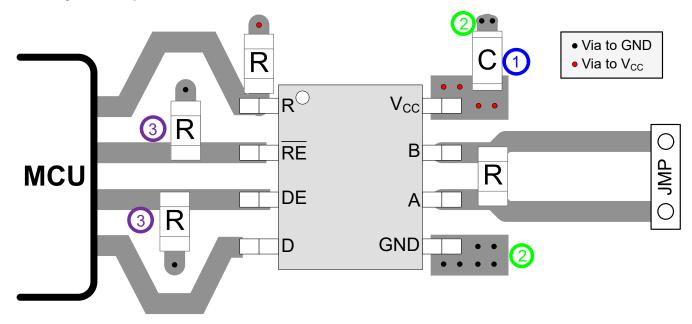


Figure 9-6. THVD2419, THVD2429 Layout Example (SOIC Package)

Submit Document Feedback



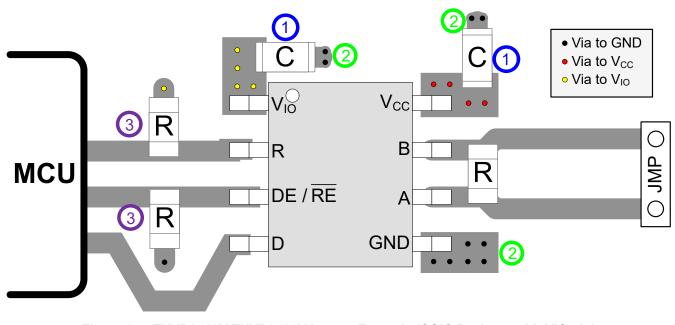


Figure 9-7. THVD2419V THVD2429V Layout Example (SOIC Package with VIO pin)

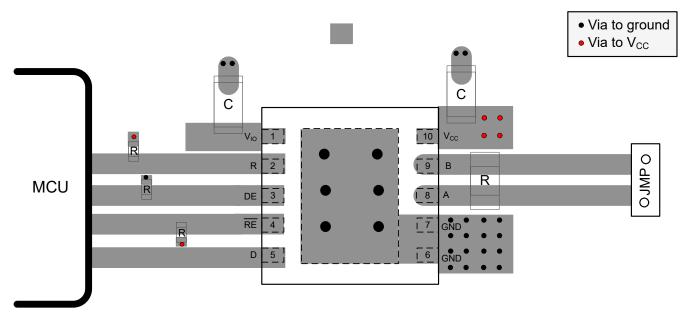


Figure 9-8. THVD2419, THVD2429 Layout Example (VSON Package)



## 10 Device and Documentation Support

### 10.1 Device Support

## 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
January 2024	*	Initial Release

# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: THVD2419 THVD2429



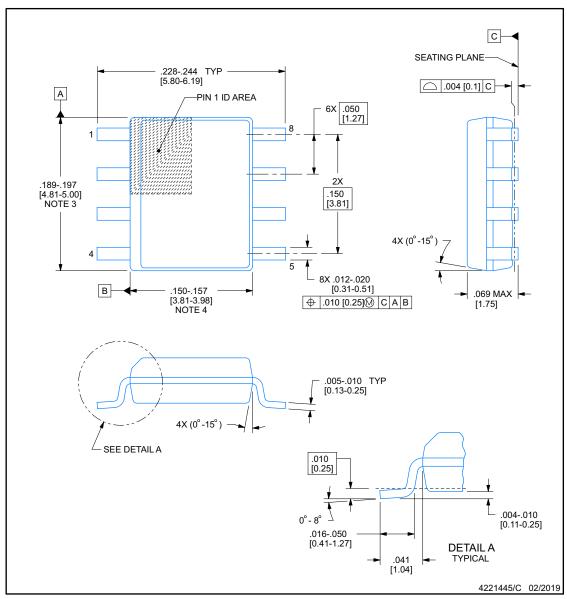
**D0008B** 



#### PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15], per side.

  4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.

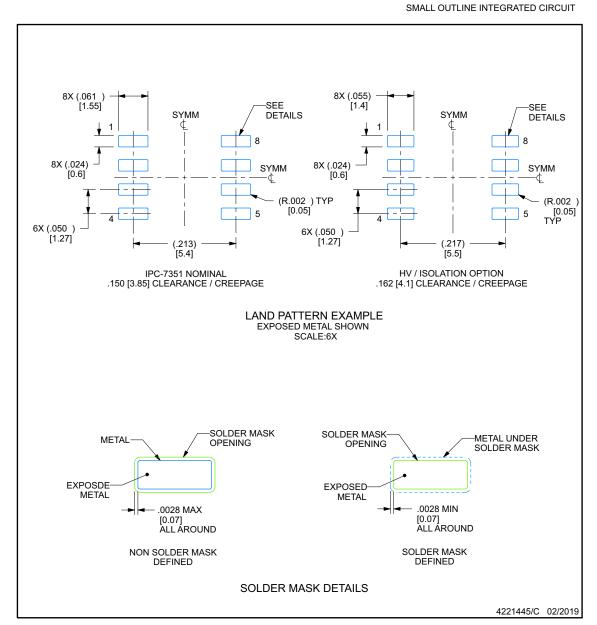




## **EXAMPLE BOARD LAYOUT**

# **D0008B**

SOIC - 1.75 mm max height



NOTES: (continued)

- Publication IPC-7351 may have alternate designs.
   Solder mask tolerances between and around signal pads can vary based on board fabrication site.

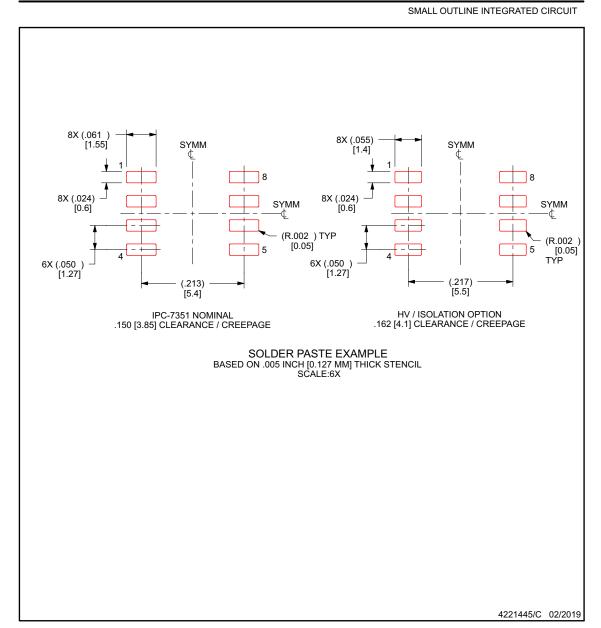




#### **EXAMPLE STENCIL DESIGN**

## **D0008B**

SOIC - 1.75 mm max height



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



**DRC0010V** 

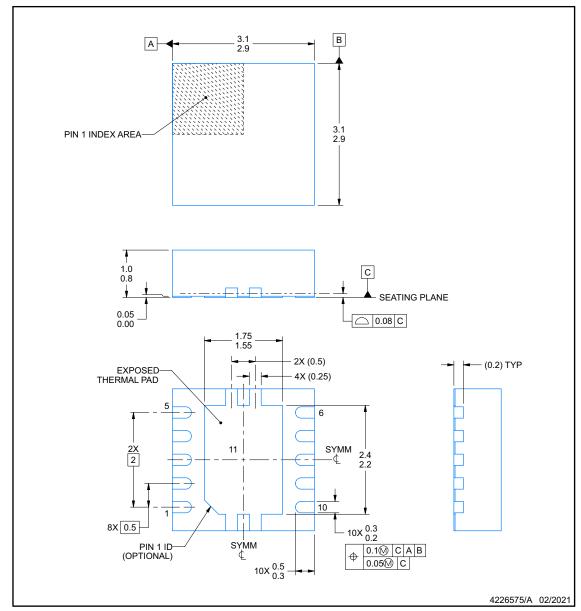




## **PACKAGE OUTLINE**

## VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



#### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



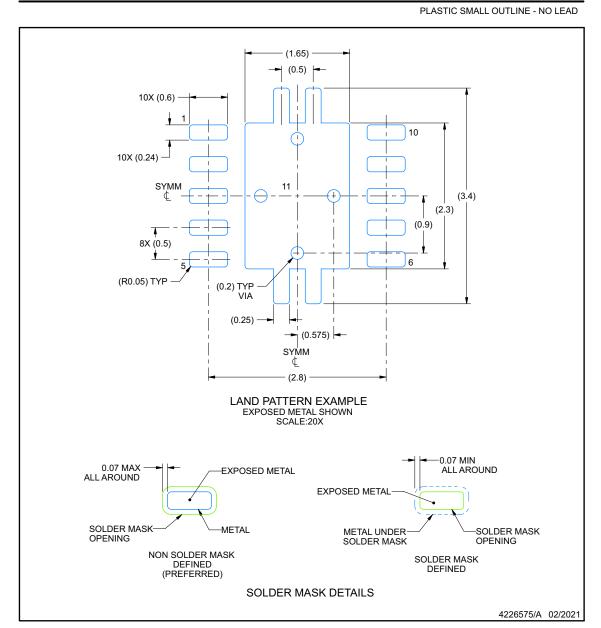
Submit Document Feedback



#### **EXAMPLE BOARD LAYOUT**

## **DRC0010V**

VSON - 1 mm max height



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

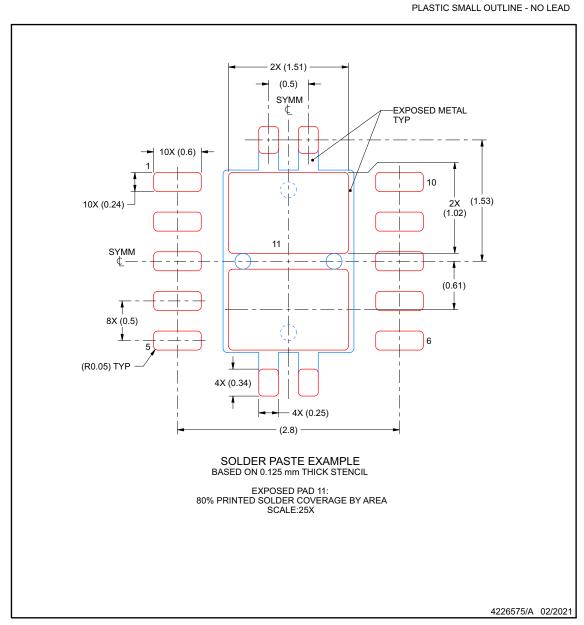




# **EXAMPLE STENCIL DESIGN**

# **DRC0010V**

VSON - 1 mm max height



NOTES: (continued)

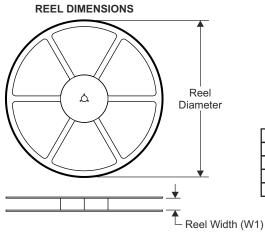
Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



Submit Document Feedback



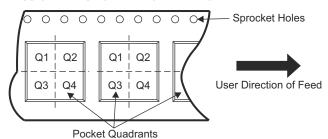
## 12.1 Tape and Reel Information



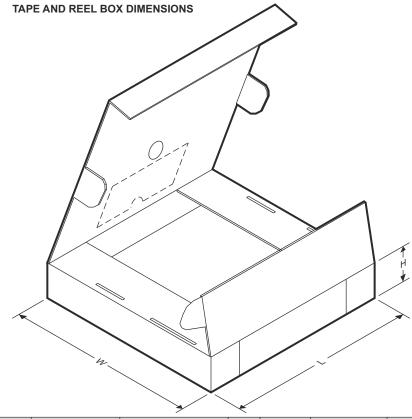
# TAPE DIMENSIONS KO P1 BO W Cavity AO Cavity

Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
PTHVD2419DR PTHVD2419VDR PTHVD2429DR PTHVD2429VDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
PTHVD2419DRCR PTHVD2429DRCR	VSON	DRC	10	5000	330.0	12.4	3.3	3.3	1.1	8.0	9.1	Q2



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
PTHVD2419DR PTHVD2419VDR PTHVD2429DR PTHVD2429VDR	SOIC	D	8	2500	340.5	338.1	20.6
PTHVD2419DRCR PTHVD2429DRCR	VSON	DRC	10	5000	367.0	367.0	35.0

**ADVANCE INFORMATION** 

www.ti.com 10-Feb-2024

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
PTHVD2419DRCR	ACTIVE	VSON	DRC	10	5000	TBD	Call TI	Call TI	-40 to 125		Samples
PTHVD2429DRCR	ACTIVE	VSON	DRC	10	5000	TBD	Call TI	Call TI	-40 to 125		Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



# **PACKAGE OPTION ADDENDUM**

www.ti.com 10-Feb-2024

#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated